

SiC Schottky Barrier Diode

V_R	650V
I _F	15A
Q_{C}	37nC

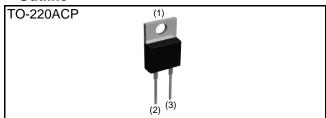
Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible
- 4) High surge current capability

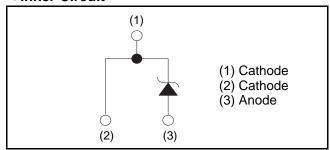
Construction

Silicon carbide epitaxial planar type

●Outline



●Inner Circuit



Packaging Specifications

	Packaging	Tube
	Reel size (mm)	-
Typo	Tape width (mm)	-
Туре	Basic ordering unit (pcs)	50
	Packing code	C9
	Marking	SCS315AH

● Absolute Maximum Ratings (T_i = 25°C)

Parameter		Symbol	Value	Unit
Reverse voltage (re	epetitive peak)	V_{RM}	650	V
Reverse voltage (DC)		V_R	650	V
Continuous forward	d current (T _c =130°C)	I _F	15	А
Surge non-	PW=10ms sinusoidal, T _j =25°C		112	А
repetitive forward	PW=10ms sinusoidal, T _j =150°C	I_{FSM}	95	А
current	PW=10μs square, T _j =25°C		410	А
Repetitive peak forward current		I _{FRM}	64 *1	А
1≦PW≦10ms, T _j =25°C		∫ i²dt	62	A ² s
i ² t value 1≦PW≦10ms, T _j =150°C		J i⁻dt	45	A ² s
Total power disspation		P_D	93 *2	W
Junction temperature		T _j	175	°C
Range of storage temperature		T_{stg}	-55 to +175	°C

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

Parameter Symbol	Cymbol	Conditions	Values			Linit
	Conditions	Min.	Тур.	Max.	Unit	
DC blocking voltage	V_{DC}	I _R =75μA	650	-	-	V
	V _F	I _F =15A,T _j =25°C	-	1.35	1.50	V
Forward voltage		I _F =15A,T _j =150°C	-	1.44	1.71	V
		I _F =15A,T _j =175°C	-	1.50	-	V
Reverse current	I _R	V _R =650V,T _j =25°C	-	0.045	75	μΑ
		V _R =650V,T _j =150°C	-	3	300	μΑ
		V _R =650V,T _j =175°C	-	9	-	μΑ
Total capacitance	С	V _R =1V,f=1MHz	-	750	-	pF
		V _R =650V,f=1MHz	-	68	-	pF
Total capacitive charge	Q_{C}	V _R =400V,di/dt=350A/μs	-	37	-	nC
Switching time	t _C	V _R =400V,di/dt=350A/μs	-	21	-	ns
Non-repetetive Avaranche Energy	E _{ava}	L=1mH	-	210	-	mJ

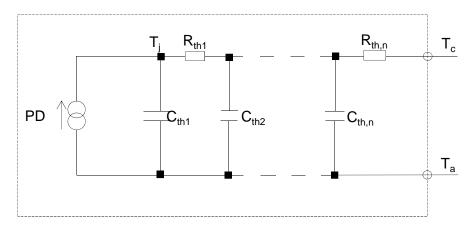
●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Тур.	Max.	Unit
Thermal resistance	R _{th(j-c)}	-	-	1.1	1.6	°C/W

●Typical Transient Thermal Characteristics

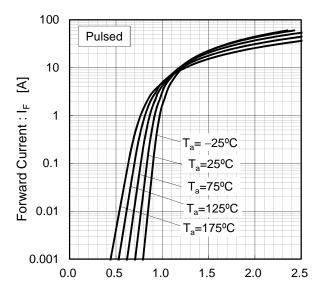
Symbol	Value	Unit
R _{th1}	9.64E-03	
R _{th2}	7.25E-02	K/W
R _{th3}	1.02E+00	

Symbol	Value	Unit
C _{th1}	4.14E-04	
C _{th2}	3.29E-04	Ws/K
C _{th3}	1.13E-03	



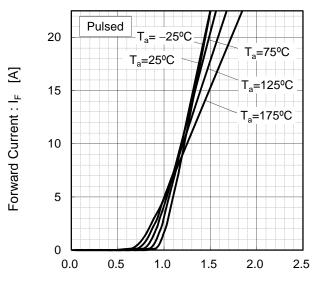
•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics



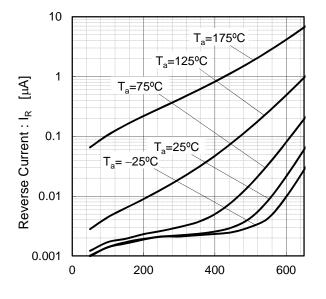
Forward Voltage : V_F [V]

Fig.2 V_F - I_F Characteristics



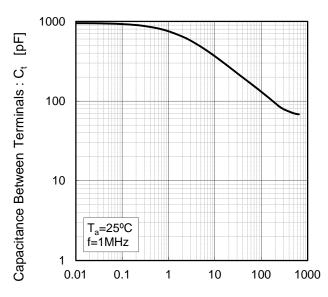
Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics



Reverse Voltage : V_R [V]

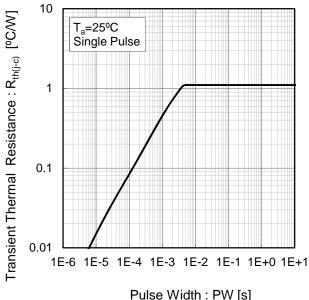
Fig.4 V_R-C_t Characteristics



Reverse Voltage : V_R [V]

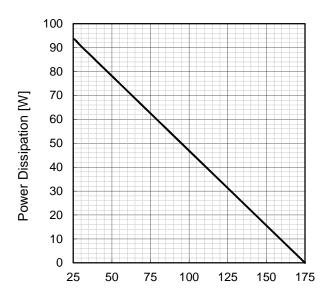
•Electrical characteristic curves

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width



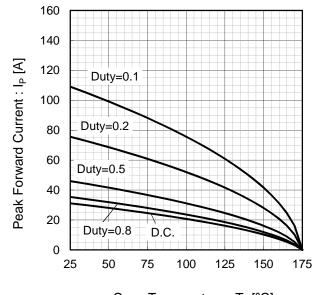
Pulse Width: PW [s]

Fig.6 Power Dissipation



Case Temperature : T_c [°C]

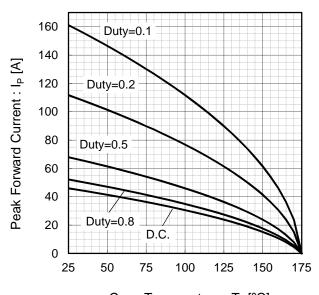
Fig.7*3 Maximum peak forward current derating curve I_P - T_c



Case Temperature : T_c [°C]

*3 Based on max Vf, max $R_{\text{th(j-c)}}$ Valid for switching of above 10kHz, excluding D.C. curve.

Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)

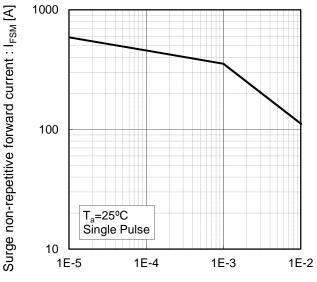


Case Temperature : T_c [°C]

*4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

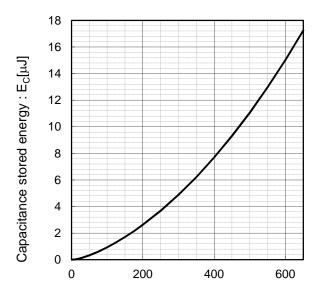
•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)



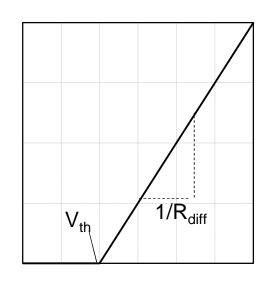
Pulse Width: PW [s]

Fig.10 Typical capacitance store energy



Reverse Voltage: V_R [V]

Fig.11 Equivalent forward current curve



Forward Voltage : V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\:T_{j}\:\right) = a_{0} + a_{1}\:T_{j} \\ &R_{diff}\left(\:T_{j}\:\right) = b_{0} + b_{1}\:T_{j} + b_{2}\:T_{j}^{2} \end{aligned}$$

Symbol	Typical Value	Unit
a_0	9.66E-01	V
a ₁	- 1.10E-03	V/°C
b_0	2.35E-02	Ω
b ₁	4.97E-05	Ω/°C
b ₂	5.12E-07	Ω /°C ²

 $\rm T_{j}$ in °C; -55 °C < $\rm T_{j} < 175^{o}C$; $\rm I_{F} < 30A$

Forward Current: IF

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